



MECHANICAL DATA

Dimensions in mm

6.35 (0.250) 8.64 (0.340) (0.145) rad 3.61 (0.142) max 4.08(0.161) (0.028) 0.71 14.48 (0.570) 14.99 (0.590) 1.27 (0.050) 1.91 (0.750) 4.83 (0.190) 5.33 (0.210) 9.14 (0.360)

POWER TRANSISTORS NPN SILICON

FEATURES

- Hermetically Packaged.
- Low Saturation Voltage
- High Gain

TO66 Package (TO-213AA)

Pin 1 = Base Pin 2 = Emitter Case = Collector

ABSOLUTE MAXIMUM RATINGS (T_{case} = 25°C unless otherwise stated)

T _{stg}	Operating and Storage Temperature Range	−65 to 200°C
	Derate 25°C	0.133W/°C
P_{D}	Total Device Dissipation at T _{case} = 25°C	20W
I_{B}	Base Current	0.5A
$I_{C(PK)}$	Peak Collector Current	2A
$I_{\mathbb{C}}$	Collector Current	1A
V_{EBO}	Emitter – Base Voltage ($I_C = 0$)	6V
V_{CEO}	Collector – Emitter Voltage $(I_B = 0)$	225V
V_{CBO}	Collector – Base Voltage	250V

Semelab PIc reserves the right to change test conditions, parameter limits and package dimensions without notice. Information furnished by Semelab is believed to be both accurate and reliable at the time of going to press. However Semelab assumes no responsibility for any errors or omissions discovered in its use. Semelab encourages customers to verify that datasheets are current before placing orders.

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ELECTRICAL CHARACTERISTICS (T_{case} = 25°C unless otherwise stated)

	Parameter	Test Conditions		Min.	Тур.	Max.	Unit		
	ELECTRICAL CHARACTERISTICS				·				
V _{CEO(BR)*}	Collector- Emitter Breakdown Voltage	$I_C = 5mA$	$I_B = 0$	225			V		
I _{CBO}	Collector Base Cut-Off Current	V _{CB} = 250V	I _E = 0			0.1	mA		
I _{CEO}	Collector Emilter Cut-Off Current	V _{CE} = 125V	$I_B = 0$			0.25	mA		
		V _{CE} = 250V	$V_{BE(OFF)} = 1.5V$			0.5	mA		
I _{CEV}	Collector Cut–Off Current	V _{CE} = 125V	$V_{BE(OFF)} = 1.5V$			1.0	mA		
			T _C = 100°C						
I _{EBO}	Emitter Base Cut-Off Current	V _{EB} = 6V				0.1	mA		
h _{FE*}	DC Current Gain	$I_C = 50 \text{mA}$	V _{CE} = 10V	30			_		
		I _C = 100mA	V _{CE} = 10V	40		200			
		I _C = 250mA	V _{CE} = 10V	25					
V _{CE(sat)*}	Collector – Emitter Saturation Voltage	I _C = 250mA	$I_B = 25mA$			2.5			
V _{BE(on)*}	Base – Emitter on Voltage	I _C = 100mA	V _{CE} = 10V			1.0	V		
DYNAMIC CHARACTERISTICS									
f _T	Transition Frequency	I _C = 100mA	V _{CE} = 10V	10		1	MHz		
			f = 10MHz				1011 12		
C _{ob}	Output Capacitance	V _{CB} = 100V	I _E = 0			20	pF		
			f = 100KHz						
h _{fe}	Small Signal Current Gain	I _C = 100mA		35			_		
			f = 1KHz						

^{*} Pulse Width $\leq 300 \mu s$, Duty Cycle < 2%

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